

### STANDARD RECOVERY DIODES

### Stud Version

#### Features

- Wide current range
- High voltage ratings up to 4500V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC types

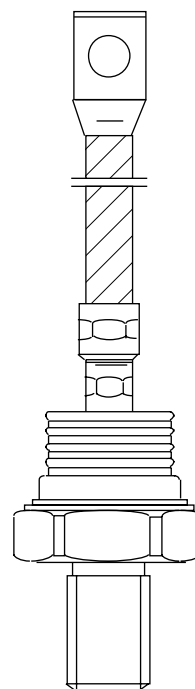
#### Typical Applications

- Converters
- Power supplies
- High power drives
- Auxiliary system supplies for traction applications

#### Major Ratings and Characteristics

Parameters	SD500N/R	Units
$I_{F(AV)}$	475	A
@ $T_C$	55	°C
$I_{F(RMS)}$	745	A
$I_{FSM}$ @ 50Hz	7500	A
@ 60Hz	7850	A
$I^2t$ @ 50Hz	281	KA <sup>2</sup> s
@ 60Hz	257	KA <sup>2</sup> s
$V_{RRM}$ range	3000 to 4500	V
$T_J$	- 40 to 150	°C

475A



case style  
B-8

**ELECTRICAL SPECIFICATIONS**

## Voltage Ratings

Type number	Voltage Code	$V_{RRM}$ , maximum repetitive peak reverse voltage V	$V_{RSM}$ , maximum non-repetitive peak rev. voltage V	$I_{RRM}$ max. @ $T_J = T_J$ max. mA
SD500N/R	30	3000	3100	50
	36	3600	3700	
	40	4000	4100	
	45	4500	4600	

## Forward Conduction

Parameter	SD500N/R	Units	Conditions
$I_{F(AV)}$ Max. average forward current @ Case temperature	475	A	180° conduction, half sine wave
	55	°C	
$I_{F(AV)}$ Max. average forward current @ Case temperature	300	A	180° conduction, half sine wave
	100	°C	
$I_{F(RMS)}$ Max. RMS forward current	745	A	DC @ 40°C case temperature
$I_{FSM}$ Max. peak, one-cycle forward, non-repetitive surge current	7500	A	t = 10ms No voltage reappplied
	7850		t = 8.3ms
	6310		t = 10ms 50% $V_{RRM}$ reappplied
	6600		t = 8.3ms
$I^2t$ Maximum $I^2t$ for fusing	281	KA <sup>2</sup> s	t = 10ms No voltage reappplied
	257		t = 8.3ms
	199		t = 10ms 50% $V_{RRM}$ reappplied
	182		t = 8.3ms
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	2810	KA <sup>2</sup> √s	t = 0.1 to 10ms, no voltage reappplied
$V_{F(TO)1}$ Low level value of threshold voltage	0.88	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}), T_J = T_J$ max.
$V_{F(TO)2}$ High level value of threshold voltage	0.97		$(I > \pi \times I_{F(AV)}), T_J = T_J$ max.
$r_{f1}$ Low level value of forward slope resistance	0.78	mΩ	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}), T_J = T_J$ max.
$r_{f2}$ High level value of forward slope resistance	0.72		$(I > \pi \times I_{F(AV)}), T_J = T_J$ max.
$V_{FM}$ Max. forward voltage drop	1.66	V	$I_{pk} = 1000A, T_J = T_J$ max, $t_p = 10ms$ sinusoidal wave

### Thermal and Mechanical Specifications

Parameter	SD500N/R	Units	Conditions
$T_J$ Max. junction operating temperature range	-40 to 150	°C	
$T_{stg}$ Max. storage temperature range	-55 to 200		
$R_{thJC}$ Max. thermal resistance, junction to case	0.1	K/W	DC operation
$R_{thCS}$ Max. thermal resistance, case to heatsink	0.04		Mounting surface, smooth, flat and greased
$T$ Max. allowed mounting torque $\pm 10\%$	50	Nm	Not lubricated threads
wt Approximate weight	454	g	
Case style	B - 8		See Outline Table

### $\Delta R_{thJC}$ Conduction

(The following table shows the increment of thermal resistance  $R_{thJC}$  when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.012	0.008	K/W	$T_J = T_{J \text{ max.}}$
120°	0.014	0.014		
90°	0.017	0.019		
60°	0.025	0.026		
30°	0.042	0.042		

### Ordering Information Table

**Device Code**

SD	50	0	N	45	P	S	C
①	②	③	④	⑤	⑥	⑦	⑧

**1**

 - Diode

**2**

 - Essential part number

**3**

 - 0 = Standard recovery

**4**

 - N = Stud Normal Polarity (Cathode to Stud)  
 R = Stud Reverse Polarity (Anode to Stud)

**5**

 - Voltage code: Code x 100 =  $V_{RRM}$  (See Voltage Ratings table)

**6**

 - P = Stud base B-8 3/4" 16UNF-2A  
 M = Stud base B-8 M24 X 1.5

**7**

 - S = Isolated lead with silicone sleeve  
 (Red = Reverse Polarity; Blue = Normal Polarity)  
 T = Threaded Top Terminal 3/8" 24UNF-2A  
 None = Non isolated lead

**8**

 - C = Ceramic Housing

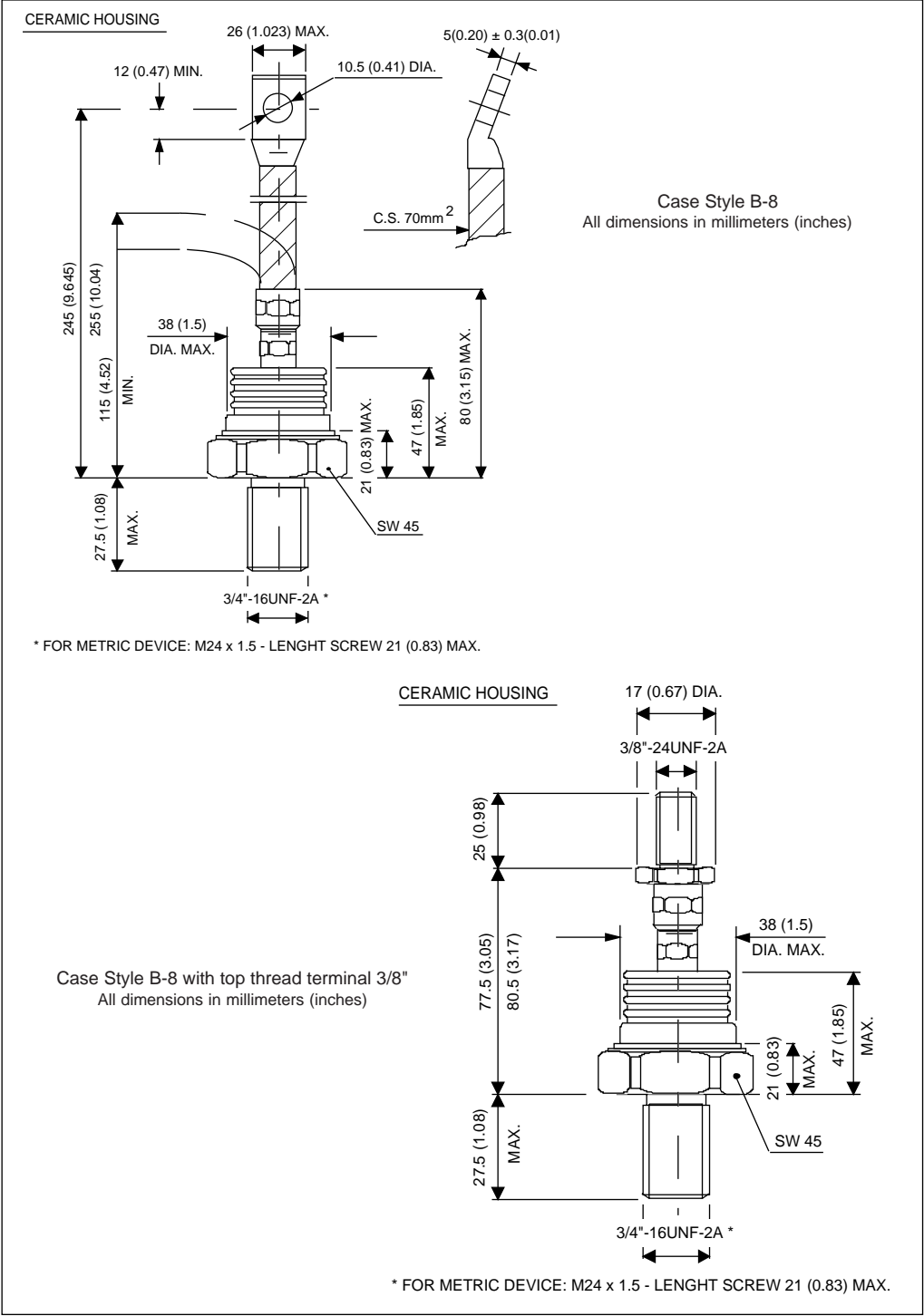
**NOTE:** Available for rotating applications (Contact factory)

**SD500N/R Series**

Bulletin I2095 rev. A 08/94

International  
**IRF** Rectifier

**Outlines Table**



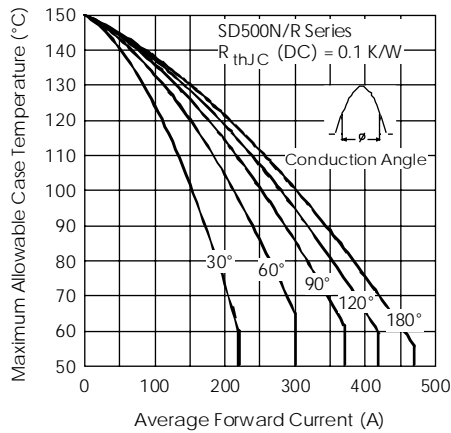


Fig. 1 - Current Ratings Characteristics

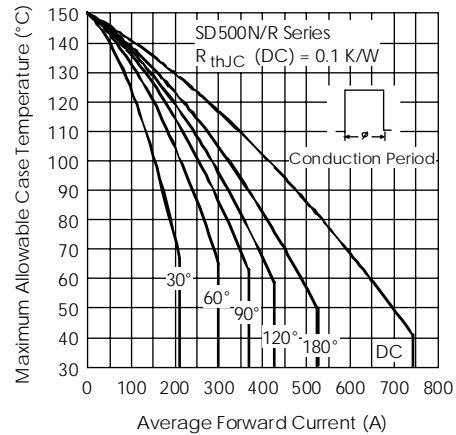


Fig. 2 - Current Ratings Characteristics

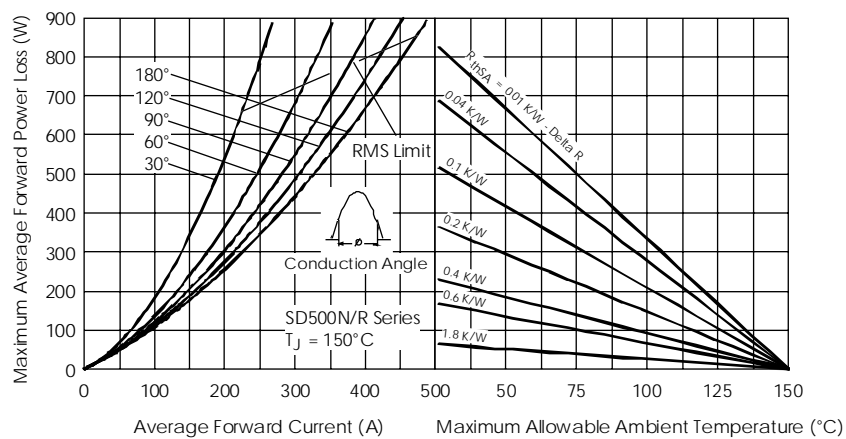


Fig. 3 - Forward Power Loss Characteristics

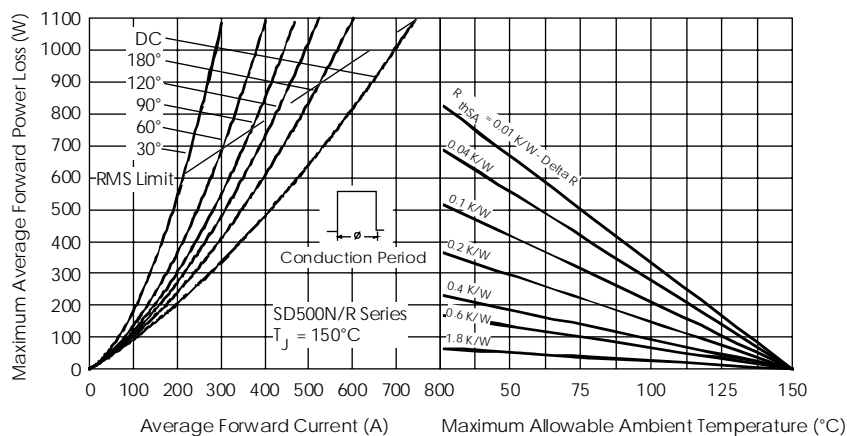


Fig. 4 - Forward Power Loss Characteristics

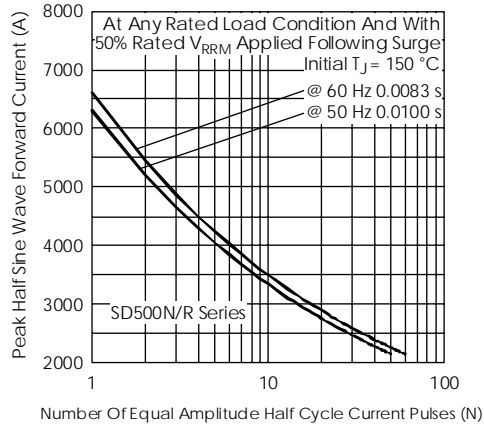


Fig. 5 - Maximum Non-Repetitive Surge Current

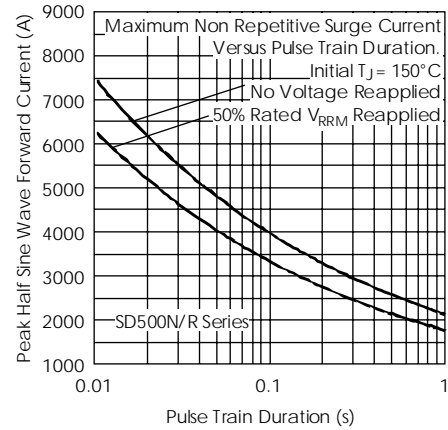


Fig. 6 - Maximum Non-Repetitive Surge Current

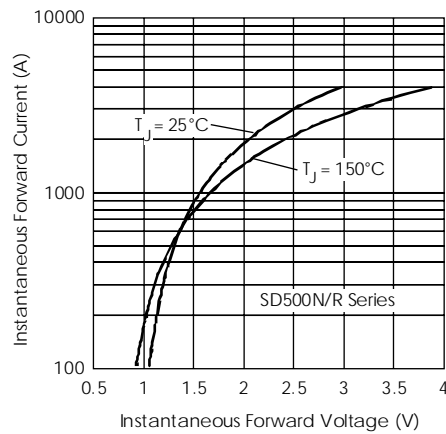
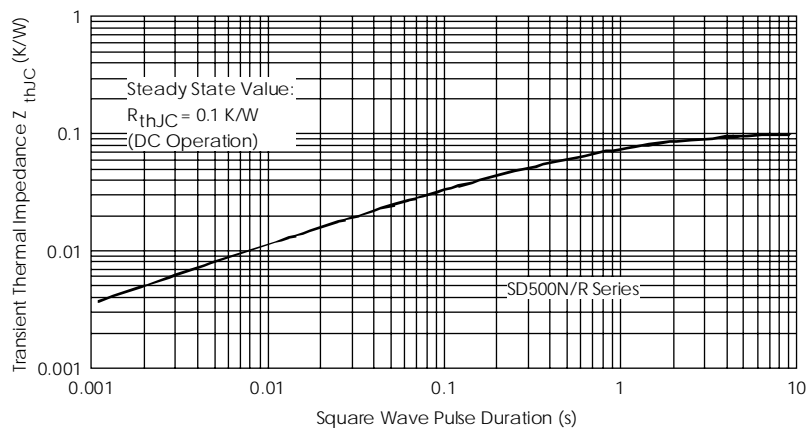


Fig. 7 - Forward Voltage Drop Characteristics

Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristics